# VS-30CTQ0.0S-M3, VS-30CTQ0.0-1-M3 Series

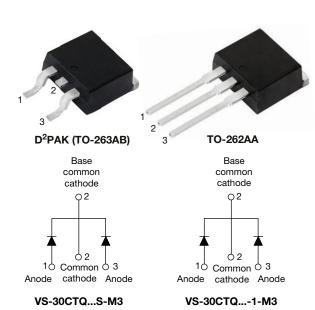
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HALOGEN

**FREE** 

# High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>R</sub>	50 V, 60 V			
V <sub>F</sub> at I <sub>F</sub>	0.56 V			
I <sub>RM</sub>	45 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
E <sub>AS</sub>	13 mJ			
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA			
Circuit configuration	Common cathode			

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Center tap configuration
- · Very low forward voltage drop
- High frequency operation
- · High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UN				
I <sub>F(AV)</sub>	Rectangular waveform	30	Α			
V <sub>RRM</sub>		50/60	V			
I <sub>FSM</sub>	$t_p = 5 \mu s sine$	1000	Α			
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.56	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-30CTQ050S-M3 VS-30CTQ050-1-M3	VS-30CTQ060S-M3 VS-30CTQ060-1-M3	UNITS	
Maximum DC reverse voltage	$V_R$	50	60	V	
Maximum working peak reverse voltage	$V_{RWM}$	50	00	V	



See fig. 7

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V<sub>RRM</sub> applied

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260

13

1.50

mJ

Α

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average	per device				30			
forward current See fig. 5 per leg		I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 105 °C	15				
Maximum peak one cycle non-repetitive		_	5 μs sine or 3 μs rect. pulse	Following any rated load	1000	A		
surge current per leg		I <sub>FSM</sub>	10 ms sine or 6 ms root pulse	condition and with rated	260			

 $\mathsf{E}_{\mathsf{AS}}$ 

 $I_{AR}$ 

10 ms sine or 6 ms rect. pulse

 $T_J = 25$  °C,  $I_{AS} = 1.50$  A, L = 11.5 mH

Current decaying linearly to zero in 1  $\mu s$ 

Frequency limited by  $T_J$  maximum  $V_A = 1.5 \times V_R$  typical

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		15 A	T <sub>.1</sub> = 25 °C	0.62	V
Maximum forward voltage drop per leg See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	30 A	1J=25 C	0.82	
	V FM (1)	15 A	T <sub>.1</sub> = 125 °C	0.56	
		30 A	1J = 125 C	0.71	
Maximum reverse leakage current per leg	ı (1)	T <sub>J</sub> = 25 °C	V Dated V	0.80	- mA
See fig. 2	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	45	
Threshold voltage	V <sub>F(TO)</sub>	T T mayimum		0.39	V
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		8.47	mΩ
Maximum junction capacitance per leg	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range	720	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body 8.0 nH			nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µs			

## Note

Non-repetitive avalanche energy per leg

Repetitive avalanche current per leg

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to 150	°C	
Maximum thermal resistance, junction to case per leg	*		DC eneration	3.25	°C/W	
Maximum thermal resistance, junction to case per package		□thJC	R <sub>thJC</sub> DC operation 1.63			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum			6 (5)	kgf · cm	
maximum				12 (10)	(lbf $\cdot$ in)	
Marking daying			Case style D <sup>2</sup> PAK (TO-263AB)		Q050S Q060S	
Marking device			Case style TO-262AA	30CTC 30CTC		

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %





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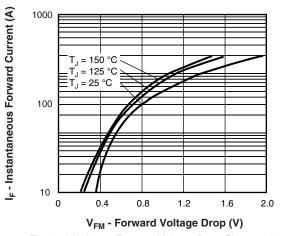


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

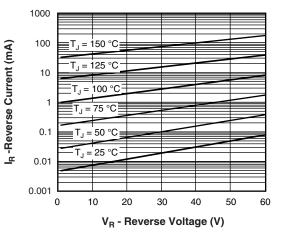


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

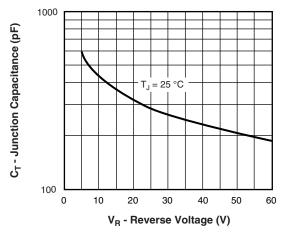


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

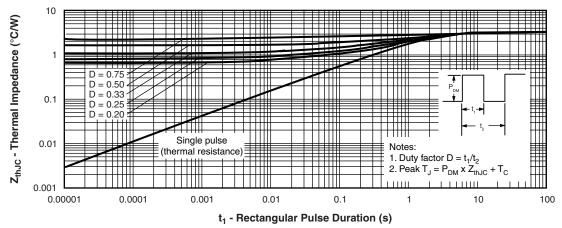


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)



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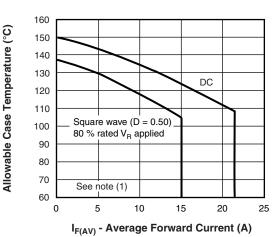


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

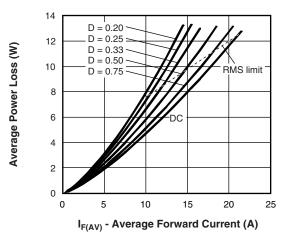


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

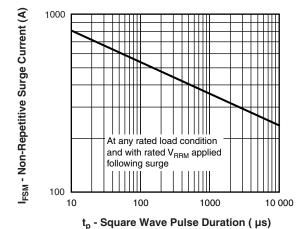


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

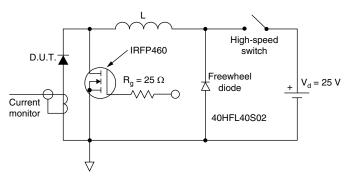


Fig. 8 - Unclamped Inductive Test Circuit

## Note

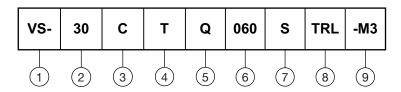
(1) Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 10 V

# VS-30CTQ0.0S-M3, VS-30CTQ0.0-1-M3 Series

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## **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

2 - Current rating (30 A)

3 - Circuit configuration: C = common cathode

**4** - T = TO-220

5 - Schottky "Q" series

- Voltage ratings - 050 = 50 V 060 = 60 V

7 - • S = D<sup>2</sup>PAK (TO-263AB)

• -1 = TO-262AA

8 - • None = tube

• TRL = tape and reel (left oriented - for D<sup>2</sup>PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D<sup>2</sup>PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMAT	ORDERING INFORMATION						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-30CTQ050S-M3	50	1000	Antistatic plastic tubes				
VS-30CTQ050STRR-M3	800	800	13" diameter reel				
VS-30CTQ050STRL-M3	800	800	13" diameter reel				
VS-30CTQ050-1-M3	50	1000	Antistatic plastic tubes				
VS-30CTQ060S-M3	50	1000	Antistatic plastic tubes				
VS-30CTQ060STRR-M3	800	800	13" diameter reel				
VS-30CTQ060STRL-M3	800	800	13" diameter reel				
VS-30CTQ060-1-M3	50	1000	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS					
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164			
Differsions	TO-262AA	www.vishay.com/doc?96165			
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444			
Fait marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information		www.vishay.com/doc?96424			



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# D<sup>2</sup>PAK

## **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

## Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

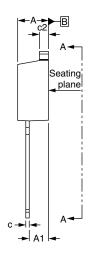


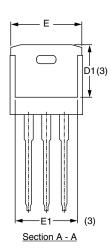
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## **TO-262**

## **DIMENSIONS** in millimeters and inches

# Modified JEDEC outline TO-262 (Datum A) (2) (3) (3) L1 D D D C C C C A (2) A (2) A (3) L2 B B B B C C C A (2)



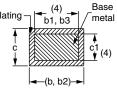


**⊕** 0.010**⋒**|A**⋒**|B

#### Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CYMPOL	MILLIN	MILLIMETERS		INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100	BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

#### Notes

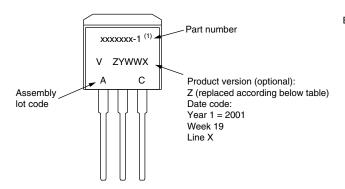
- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



# **Part Marking Information**

# Vishay Semiconductors

## **TO-262**



Example: This is a xxxxxxx-1 <sup>(1)</sup> with assembly lot code AC, assembled on WW 19, 2001

in the assembly line "X"

#### Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

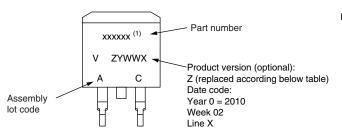
ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION		
A	Termination lead (Pb)-free		
B Totally lead (Pb)-free			
E	RoHS-compliant and termination lead (Pb)-free		
F	RoHS-compliant and totally lead (Pb)-free		
M Halogen-free, RoHS-compliant and termination lead (Pb)-free			
N	Halogen-free, RoHS-compliant and totally lead (Pb)-free		
G	Green		



# **Part Marking Information**

Vishay Semiconductors

## D<sup>2</sup>PAK



Example: This is a xxxxxx <sup>(1)</sup> with assembly lot code AC, assembled on WW 02, 2010

#### Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION		
А	Termination lead (Pb)-free		
B Totally lead (Pb)-free			
E	RoHS-compliant and termination lead (Pb)-free		
F RoHS-compliant and totally lead (Pb)-free			
M	Halogen-free, RoHS-compliant, and termination lead (Pb)-free		
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free		
G	Green		



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